

TC4086BP

C²MOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC

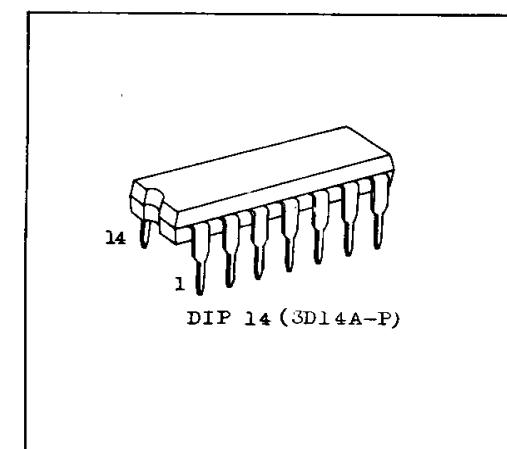
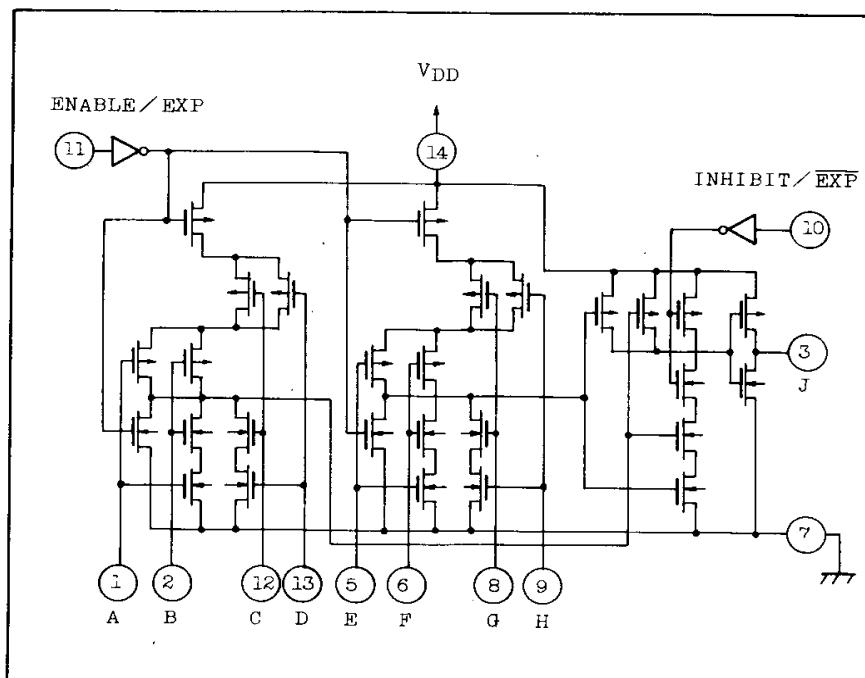
TC4086BP EXPANDABLE 4-WIDE 2-INPUT AND-OR-INVERT GATE

TC4086BP contains four 2 input AND gates and one OR gate which logically adds (OR) all the AND gates having an expander input to form AND-OR-select gate, and the output is inverted. INH/EXP input and ENABLE/EXP input are the expander inputs to connect other AND gates and select gate and these can be used as INHIBIT input to inhibit the select operation besides of the expander function.

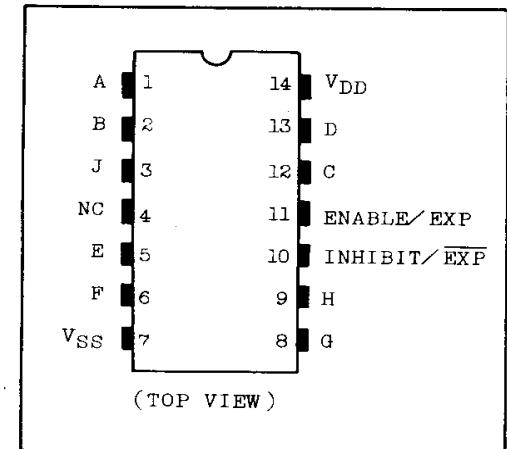
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V _{DD}	V _{SS} -0.5 ~ V _{SS} +20	V
Input Voltage	V _{IN}	V _{SS} -0.5 ~ V _{DD} +0.5	V
Output Voltage	V _{OUT}	V _{SS} -0.5 ~ V _{DD} +0.5	V
DC Input Current	I _{IN}	±10	mA
Power Dissipation	P _D	300	mW
Operating Temperature Range	T _A	-40 ~ 85	°C
Storage Temperature Range	T _{STG}	-65 ~ 150	°C
Lead Temp./Time	T _{SOL}	260°C • 10sec	

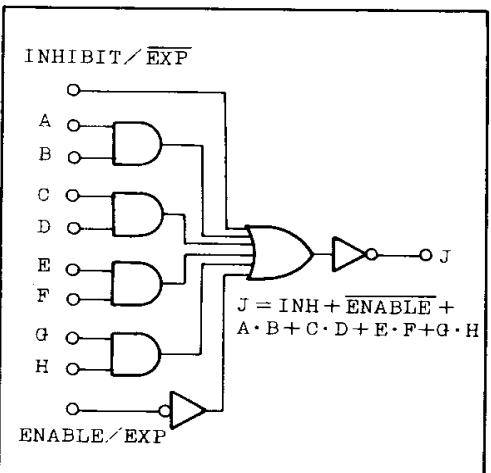
CIRCUIT DIAGRAM



PIN ASSIGNMENT



LOGIC DIAGRAM



RECOMMENDED OPERATING CONDITIONS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL		MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	V _{DD}		3	-	18	V
Input Voltage	V _{IN}		0	-	V _{DD}	V

STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYM-BOL	TEST CONDITION	V _{DD} (V)	-40°C		25°C			85°C		UNIT	
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Output Voltage	V _{OH}	I _{OUT} <1μA V _{IN} =V _{SS} , V _{DD}	5	4.95	-	4.95	5.00	-	4.95	-	V	
			10	9.95	-	9.95	10.00	-	9.95	-		
			15	14.95	-	14.95	15.00	-	14.95	-		
Low-Level Output Voltage	V _{OL}	I _{OUT} <1μA V _{IN} =V _{SS} , V _{DD}	5	-	0.05	-	0.00	0.05	-	0.05	V	
			10	-	0.05	-	0.00	0.05	-	0.05		
			15	-	0.05	-	0.00	0.05	-	0.05		
Output High Current	I _{OH}	V _{OH} =4.6V V _{OH} =2.5V V _{OH} =9.5V V _{OH} =13.5V	5	-0.61	-	-0.51	-1.0	-	-0.42	-	mA	
			5	-2.5	-	-2.1	-4.0	-	-1.7	-		
			10	-1.5	-	-1.3	-2.2	-	-1.1	-		
			15	-4.0	-	-3.4	-9.0	-	-2.8	-		
		V _{IN} =V _{SS} , V _{DD}										
Output Low Current	I _{OL}	V _{OL} =0.4V V _{OL} =0.5V V _{OL} =1.5V	5	0.61	-	0.51	1.5	-	0.42	-	mA	
			10	1.5	-	1.3	3.8	-	1.1	-		
			15	4.0	-	3.4	15.0	-	2.8	-		
		V _{IN} =V _{SS} , V _{DD}										
Input High Voltage	V _{IH}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V	5	3.5	-	3.5	2.75	-	3.5	-	V	
			10	7.0	-	7.0	5.5	-	7.0	-		
			15	11.0	-	11.0	8.25	-	11.0	-		
		I _{OUT} <1μA										
Input Low Voltage	V _{IL}	V _{OUT} =0.5V, 4.5V V _{OUT} =1.0V, 9.0V V _{OUT} =1.5V, 13.5V	5	-	1.5	-	2.25	1.5	-	1.5	V	
			10	-	3.0	-	4.5	3.0	-	3.0		
			15	-	4.0	-	6.75	4.0	-	4.0		
		I _{OUT} <1μA										
Input Current	"H" Level	I _{IH}	V _{IH} =18V	18	-	0.1	-	10 ⁻⁵	0.1	-	1.0	μA
	"L" Level	I _{IL}	V _{IL} =0V	18	-	-0.1	-	-10 ⁻⁵	-0.1	-	-1.0	

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STATIC ELECTRICAL CHARACTERISTICS (V_{SS}=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{DD} (V)	-40°C		25°C			85°C		UNIT
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
Quiescent Device Current	I _{DD}	V _{IN} =V _{SS} , V _{DD} *	5	-	1	-	0.001	1	-	7.5	
			10	-	2	-	0.002	2	-	15	μA
			15	-	4	-	0.004	4	-	30	

* All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (T_A=25°C, V_{SS}=0V, C_L=50pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{DD} (V)	MIN.	TYP.	MAX.	UNIT
Output Transition Time (Low to High)	t _{TLH}		5	-	80	200	ns
			10	-	50	100	
			15	-	40	80	
Output Transition Time (High to Low)	t _{THL}		5	-	80	200	
			10	-	50	100	
			15	-	40	80	
Propagation Delay Time (DATA - OUT)	t _{pLH}		5	-	110	450	ns
			10	-	45	180	
			15	-	30	120	
Propagation Delay Time (DATA - OUT)	t _{pHL}		5	-	110	450	
			10	-	45	180	
			15	-	35	120	
Propagation Delay Time (INHIBIT - OUT)	t _{pLH}		5	-	75	300	ns
			10	-	35	120	
			15	-	25	80	
Propagation Delay Time (INHIBIT - OUT)	t _{pHL}		5	-	70	300	
			10	-	30	120	
			15	-	25	80	
Propagation Delay Time (ENABLE - OUT)	t _{pLH}		5	-	95	300	ns
			10	-	40	120	
			15	-	30	80	
Propagation Delay Time (ENABLE - OUT)	t _{pHL}		5	-	90	300	
			10	-	40	120	
			15	-	30	80	
Input Capacitance	C _{IN}			-	5	7.5	pF

WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

